# 74LVC1G57-Q100

# Low-power configurable multiple function gate

Rev. 5 — 18 August 2023

**Product data sheet** 

## 1. General description

The 74LVC1G57-Q100 is a configurable multiple function gate with Schmitt-trigger inputs. The device can be configured as any of the following logic functions AND, OR, NAND, NOR, XNOR, inverter and buffer; using the 3-bit input. All inputs can be connected directly to  $V_{\rm CC}$  or GND. Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V environments.

This device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

#### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 1.65 V to 5.5 V
- Overvoltage tolerant inputs to 5.5 V
- · High noise immunity
- ±24 mA output drive (V<sub>CC</sub> = 3.0 V)
- · CMOS low power dissipation
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- Complies with JEDEC standard:
  - JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8B/JESD36 (2.7 V to 3.6 V).
- · ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V

# 3. Ordering information

**Table 1. Ordering information** 

| Type number      | Package           | ackage          |   |               |  |  |  |  |
|------------------|-------------------|-----------------|---|---------------|--|--|--|--|
|                  | Temperature range | Version         |   |               |  |  |  |  |
| 74LVC1G57GW-Q100 | -40 °C to +125 °C | TSSOP6          | plastic thin shrink small outline package;<br>6 leads; body width 1.25 mm | SOT363-2      |  |  |  |  |
| 74LVC1G57GV-Q100 | -40 °C to +125 °C | SC-74;<br>TSOP6 | plastic surface-mounted package; 6 leads                                  | <u>SOT457</u> |  |  |  |  |



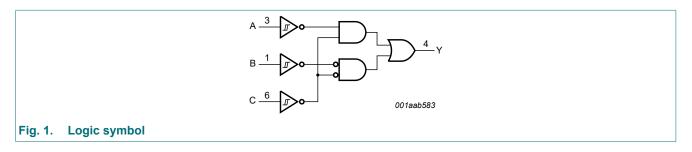
# 4. Marking

#### Table 2. Marking

| Type number      | Marking code [1] |
|------------------|------------------|
| 74LVC1G57GW-Q100 | YC               |
| 74LVC1G57GV-Q100 | V57              |

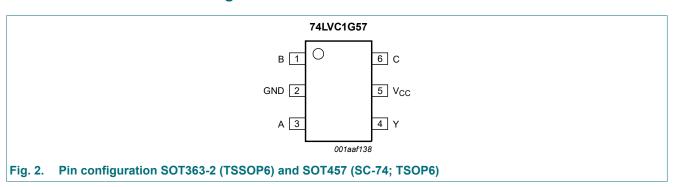
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 5. Functional diagram



# 6. Pinning information

## 6.1. Pinning



## 6.2. Pin description

Table 3. Pin description

| Symbol          | Pin | Description    |
|-----------------|-----|----------------|
| В               | 1   | data input     |
| GND             | 2   | ground (0 V)   |
| A               | 3   | data input     |
| Υ               | 4   | data output    |
| V <sub>CC</sub> | 5   | supply voltage |
| С               | 6   | data input     |

# 7. Functional description

#### **Table 4. Function table**

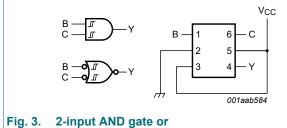
 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$ 

| Input |   |   | Output |
|-------|---|---|--------|
| С     | В | A | Υ      |
| L     | L | L | Н      |
| L     | L | Н | L      |
| L     | Н | L | Н      |
| L     | Н | Н | L      |
| Н     | L | L | L      |
| Н     | L | Н | L      |
| Н     | Н | L | Н      |
| Н     | Н | Н | Н      |

## 7.1. Logic configurations

**Table 5. Function selection table** 

| Logic function                        | Figure                |  |  |  |  |
|---------------------------------------|-----------------------|--|--|--|--|
| 2-input AND                           | see Fig. 3            |  |  |  |  |
| 2-input AND with both inputs inverted | see Fig. 6            |  |  |  |  |
| 2-input NAND with inverted input      | see Fig. 4 and Fig. 5 |  |  |  |  |
| 2-input OR with inverted input        | see Fig. 4 and Fig. 5 |  |  |  |  |
| 2-input NOR                           | see Fig. 6            |  |  |  |  |
| 2-input NOR with both inputs inverted | see Fig. 3            |  |  |  |  |
| 2-input XNOR                          | see Fig. 7            |  |  |  |  |
| Inverter                              | see Fig. 8            |  |  |  |  |
| Buffer                                | see Fig. 9            |  |  |  |  |



2-input NOR gate with both inputs inverted

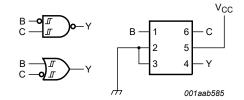


Fig. 4. 2-input NAND gate with input B inverted or 2-input OR gate with inverted C input

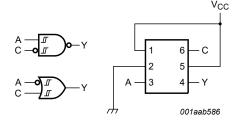


Fig. 5. 2-input NAND gate with input C inverted or 2-input OR gate with inverted A input

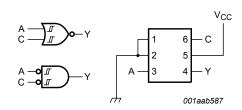
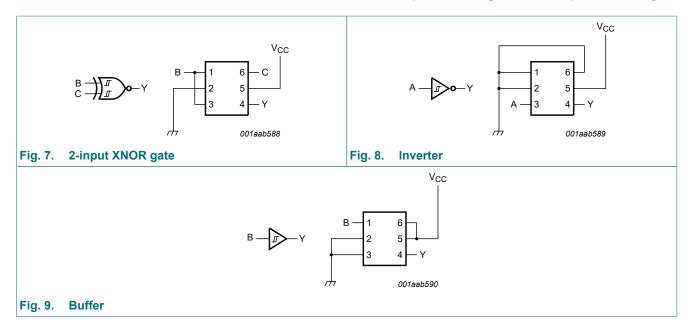


Fig. 6. 2-input NOR gate or 2-input AND gate with both inputs inverted



## 8. Limiting values

#### **Table 6. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter               | Conditions   | Min  | Max  | Unit |
|------------------|-------------------------|--|------|------|------|
| V <sub>CC</sub>  | supply voltage          |  | -0.5 | +6.5 | V    |
| I <sub>IK</sub>  | input clamping current  | V <sub>I</sub> < 0 V                                     | -50  | -    | mA   |
| VI               | input voltage           | [1]  | -0.5 | +6.5 | V    |
| I <sub>OK</sub>  | output clamping current | V <sub>O</sub> > V <sub>CC</sub> or V <sub>O</sub> < 0 V | -    | ±50  | mA   |
| Vo               | output voltage          | Active mode [1]  | -0.5 | +6.5 | V    |
|                  |                         | Power-down mode; V <sub>CC</sub> = 0 V [1]               | -0.5 | +6.5 | V    |
| I <sub>O</sub>   | output current          | V <sub>O</sub> = 0 V to V <sub>CC</sub>                  | -    | ±50  | mA   |
| I <sub>CC</sub>  | supply current          |  | -    | +100 | mA   |
| I <sub>GND</sub> | ground current          |  | -100 | -    | mA   |
| T <sub>stg</sub> | storage temperature     |  | -65  | +150 | °C   |
| P <sub>tot</sub> | total power dissipation | T <sub>amb</sub> = -40 °C to +125 °C [2]                 | -    | 250  | mW   |

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

# 9. Recommended operating conditions

Table 7. Recommended operating conditions

| rabio 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. 1. |                     |  |      |     |                 |      |  |
|--|---------------------|--|------|-----|-----------------|------|--|
| Symbol                                       | Parameter           | Conditions                             | Min  | Тур | Max             | Unit |  |
| V <sub>CC</sub>                              | supply voltage      |  | 1.65 | -   | 5.5             | V    |  |
| VI   | input voltage       |  | 0    | -   | 5.5             | V    |  |
| Vo   | output voltage      | Active mode                            | 0    | -   | V <sub>CC</sub> | V    |  |
|  |                     | Power-down mode; V <sub>CC</sub> = 0 V | 0    | -   | 5.5             | V    |  |
| T <sub>amb</sub>                             | ambient temperature |  | -40  | -   | +125            | °C   |  |

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<sup>[2]</sup> For SOT363-2 (TSSOP6) package: P<sub>tot</sub> derates linearly with 3.7 mW/K above 83 °C. For SOT457 (SC-74; TSOP6) package: P<sub>tot</sub> derates linearly with 4.1 mW/K above 89 °C.

## 10. Static characteristics

#### **Table 8. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter                    | Conditions  | -40                   | -40 °C to +85 °C |      |                       | -40 °C to +125 °C |    |
|------------------|------------------------------|---|-----------------------|------------------|------|-----------------------|-------------------|----|
|                  |                              |   | Min                   | Typ [1]          | Max  | Min                   | Max               |    |
| V <sub>OL</sub>  | LOW-level output             | $V_I = V_{T+}$ or $V_{T-}$  |                       |                  |      |                       |                   |    |
|                  | voltage                      | I <sub>O</sub> = 100 μA;<br>V <sub>CC</sub> = 1.65 V to 5.5 V                                       | -                     | -                | 0.1  | -                     | 0.1               | V  |
|                  |                              | I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V   | -                     | -                | 0.45 | -                     | 0.7               | V  |
|                  |                              | $I_O = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$  | -                     | -                | 0.3  | -                     | 0.45              | V  |
|                  |                              | I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V   | -                     | -                | 0.4  | -                     | 0.6               | V  |
|                  |                              | $I_O = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$   | -                     | -                | 0.55 | -                     | 0.8               | V  |
|                  |                              | $I_O = 32 \text{ mA}; V_{CC} = 4.5 \text{ V}$   | -                     | -                | 0.55 | -                     | 0.8               | V  |
| V <sub>OH</sub>  | HIGH-level                   | $V_I = V_{T+}$ or $V_{T-}$  |                       |                  |      |                       |                   |    |
|                  | output voltage               | I <sub>O</sub> = -100 μA;<br>V <sub>CC</sub> = 1.65 V to 5.5 V                                      | V <sub>CC</sub> - 0.1 | -                | -    | V <sub>CC</sub> - 0.1 | -                 | V  |
|                  |                              | I <sub>O</sub> = -4 mA; V <sub>CC</sub> = 1.65 V  | 1.2                   | -                | -    | 0.95                  | -                 | V  |
|                  |                              | $I_O = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$   | 1.9                   | -                | -    | 1.7                   | -                 | V  |
|                  |                              | $I_O = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$  | 2.2                   | -                | -    | 1.9                   | -                 | V  |
|                  |                              | $I_O = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$  | 2.3                   | -                | -    | 2.0                   | -                 | V  |
|                  |                              | $I_O = -32 \text{ mA}; V_{CC} = 4.5 \text{ V}$  | 3.8                   | -                | -    | 3.4                   | -                 | V  |
| l <sub>l</sub>   | input leakage<br>current     | V <sub>I</sub> = 5.5 V or GND;<br>V <sub>CC</sub> = 0 V to 5.5 V                                    | -                     | ±0.1             | ±1   | -                     | ±1                | μA |
| I <sub>OFF</sub> | power-off<br>leakage current | $V_{I}$ or $V_{O} = 5.5 \text{ V}$ ; $V_{CC} = 0 \text{ V}$   | -                     | ±0.1             | ±2   | -                     | ±2                | μA |
| I <sub>CC</sub>  | supply current               | V <sub>I</sub> = 5.5 V or GND; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 1.65 V to 5.5 V           | -                     | 0.1              | 4    | -                     | 4                 | μA |
| ΔI <sub>CC</sub> | additional supply current    | V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A;<br>V <sub>CC</sub> = 2.3 V to 5.5 V | -                     | 5                | 500  | -                     | 500               | μΑ |
| Cı               | input capacitance            |   | -                     | 2.5              | -    | -                     | -                 | pF |

<sup>[1]</sup> Typical values are measured at maximum  $V_{CC}$  and  $T_{amb}$  = 25 °C.

# 11. Dynamic characteristics

#### **Table 9. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 11.

| Symbol          | Parameter                     | Conditions  | -40 | -40 °C to +85 °C |      | -40 °C to +125 °C |      | Unit |
|-----------------|-------------------------------|---|-----|------------------|------|-------------------|------|------|
|                 |                               |   | Min | Typ [1]          | Max  | Min               | Max  |      |
| t <sub>pd</sub> | propagation delay             | A, B, C to Y; see <u>Fig. 10</u> [2]                      |     |                  |      |                   |      |      |
|                 |                               | V <sub>CC</sub> = 1.65 V to 1.95 V                        | 1.0 | 6.0              | 14.4 | 1.0               | 18   | ns   |
|                 |                               | V <sub>CC</sub> = 2.3 V to 2.7 V                          | 0.5 | 3.5              | 8.3  | 0.5               | 10.4 | ns   |
|                 |                               | V <sub>CC</sub> = 2.7 V                                   | 0.5 | 4.2              | 8.5  | 0.5               | 10.6 | ns   |
|                 |                               | V <sub>CC</sub> = 3.0 V to 3.6 V                          | 0.5 | 3.8              | 6.3  | 0.5               | 7.9  | ns   |
|                 |                               | V <sub>CC</sub> = 4.5 V to 5.5 V                          | 0.5 | 3.0              | 5.1  | 0.5               | 6.4  | ns   |
| C <sub>PD</sub> | power dissipation capacitance | $V_{CC} = 3.3 \text{ V}; V_I = \text{GND to } V_{CC}$ [3] | -   | 22               | -    | -                 | -    | pF   |

- Typical values are measured at nominal  $V_{CC}$  and at  $T_{amb}$  = 25 °C.
- $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

 $f_o$  = output frequency in MHz;

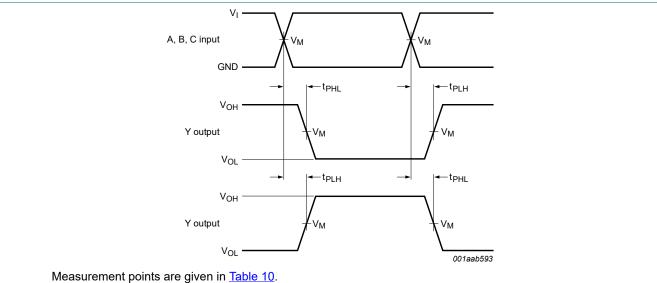
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$ 

#### 11.1. Waveforms and test circuit

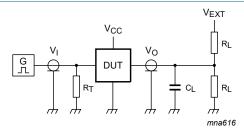


V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage levels that occur with the output load.

Fig. 10. Input A, B and C to output Y propagation delay times

Table 10. Measurement points

| Supply voltage   | Input                 | Input           |                       |
|------------------|-----------------------|-----------------|-----------------------|
| V <sub>CC</sub>  | V <sub>M</sub>        | V <sub>I</sub>  | V <sub>M</sub>        |
| 1.65 V to 1.95 V | 0.5 × V <sub>CC</sub> | V <sub>CC</sub> | 0.5 × V <sub>CC</sub> |
| 2.3 V to 2.7 V   | 0.5 × V <sub>CC</sub> | V <sub>CC</sub> | 0.5 × V <sub>CC</sub> |
| 2.7 V            | 1.5 V                 | 2.7 V           | 1.5 V                 |
| 3.0 V to 3.6 V   | 1.5 V                 | 2.7 V           | 1.5 V                 |
| 4.5 V to 5.5 V   | 0.5 × V <sub>CC</sub> | V <sub>CC</sub> | 0.5 × V <sub>CC</sub> |



Measurement points are given in Table 11.

Definitions test circuit:

R<sub>L</sub> = Load resistance;

C<sub>L</sub> = Load capacitance including jig and probe capacitance;

 $R_{T}$  = Termination resistance should be equal to output impedance  $Z_{o}$  of the pulse generator;

V<sub>EXT</sub> = External voltage for measuring switching times.

Fig. 11. Test circuit for measuring switching times

Table 11. Test data

| Supply voltage   | Input           |             | Load  | V <sub>EXT</sub> |                                     |
|------------------|-----------------|-------------|-------|------------------|-------------------------------------|
| V <sub>CC</sub>  | V <sub>I</sub>  | $t_r = t_f$ | CL    | $R_L$            | t <sub>PLH</sub> , t <sub>PHL</sub> |
| 1.65 V to 1.95 V | V <sub>CC</sub> | ≤ 2.0 ns    | 30 pF | 1 kΩ             | open                                |
| 2.3 V to 2.7 V   | V <sub>CC</sub> | ≤ 2.0 ns    | 30 pF | 500 Ω            | open                                |
| 2.7 V            | 2.7 V           | ≤ 2.5 ns    | 50 pF | 500 Ω            | open                                |
| 3.0 V to 3.6 V   | 2.7 V           | ≤ 2.5 ns    | 50 pF | 500 Ω            | open                                |
| 4.5 V to 5.5 V   | V <sub>CC</sub> | ≤ 2.5 ns    | 50 pF | 500 Ω            | open                                |

## 12. Transfer characteristics

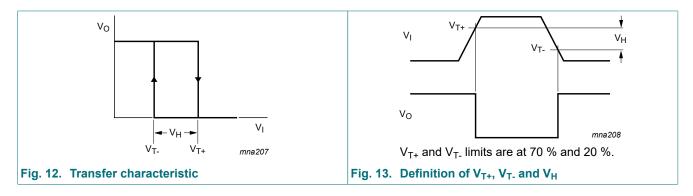
#### **Table 12. Transfer characteristics**

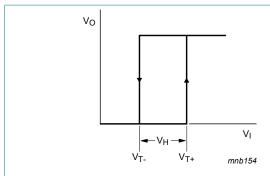
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter                        | Conditions   | -40  | -40 °C to +85 °C |      |      | -40 °C to +125 °C |   |  |
|------------------|----------------------------------|--|------|------------------|------|------|-------------------|---|--|
|                  |                                  |  | Min  | Typ [1]          | Max  | Min  | Max               |   |  |
| V <sub>T+</sub>  | positive-going threshold voltage | see Fig. 12, Fig. 13, Fig. 14 and Fig. 15  |      |                  |      |      |                   |   |  |
|                  |                                  | V <sub>CC</sub> = 1.8 V  | 0.70 | 1.02             | 1.20 | 0.67 | 1.20              | V |  |
|                  |                                  | V <sub>CC</sub> = 2.3 V  | 1.11 | 1.42             | 1.60 | 1.08 | 1.60              | V |  |
|                  |                                  | V <sub>CC</sub> = 3.0 V  | 1.50 | 1.79             | 2.00 | 1.47 | 2.00              | V |  |
|                  |                                  | V <sub>CC</sub> = 4.5 V  | 2.16 | 2.52             | 2.74 | 2.13 | 2.74              | V |  |
|                  |                                  | V <sub>CC</sub> = 5.5 V  | 2.61 | 2.99             | 3.33 | 2.58 | 3.33              | V |  |
| V <sub>T</sub> - | negative-going threshold voltage | see Fig. 12, Fig. 13, Fig. 14<br>and Fig. 15   |      |                  |      |      |                   |   |  |
|                  |                                  | V <sub>CC</sub> = 1.8 V  | 0.30 | 0.53             | 0.72 | 0.30 | 0.75              | V |  |
|                  |                                  | V <sub>CC</sub> = 2.3 V  | 0.58 | 0.77             | 1.00 | 0.58 | 1.03              | V |  |
|                  |                                  | V <sub>CC</sub> = 3.0 V  | 0.80 | 1.04             | 1.30 | 0.80 | 1.33              | V |  |
|                  |                                  | V <sub>CC</sub> = 4.5 V  | 1.21 | 1.55             | 1.90 | 1.21 | 1.93              | V |  |
|                  |                                  | V <sub>CC</sub> = 5.5 V  | 1.45 | 1.86             | 2.29 | 1.45 | 2.32              | V |  |
| $V_{H}$          | hysteresis voltage               | (V <sub>T+</sub> - V <sub>T-</sub> ); see <u>Fig. 12</u> ,<br><u>Fig. 13</u> , <u>Fig. 14</u> and <u>Fig. 15</u> |      |                  |      |      |                   |   |  |
|                  |                                  | V <sub>CC</sub> = 1.8 V  | 0.30 | 0.48             | 0.62 | 0.23 | 0.62              | V |  |
|                  |                                  | V <sub>CC</sub> = 2.3 V  | 0.40 | 0.64             | 0.80 | 0.34 | 0.80              | V |  |
|                  |                                  | V <sub>CC</sub> = 3.0 V  | 0.50 | 0.75             | 1.00 | 0.44 | 1.00              | V |  |
|                  |                                  | V <sub>CC</sub> = 4.5 V  | 0.71 | 0.97             | 1.20 | 0.65 | 1.20              | V |  |
|                  |                                  | V <sub>CC</sub> = 5.5 V  | 0.71 | 1.13             | 1.40 | 0.65 | 1.40              | V |  |

<sup>[1]</sup> Typical values are measured at  $T_{amb}$  = 25 °C.

### 12.1. Waveforms transfer characteristics





V<sub>1</sub> V<sub>T</sub> V<sub>H</sub> V<sub>O</sub> mnb155

 $V_{T+}$  and  $V_{T-}$  limits are at 70 % and 20 %.

Fig. 14. Transfer characteristic

Fig. 15. Definition of  $V_{T+}$ ,  $V_{T-}$  and  $V_H$ 

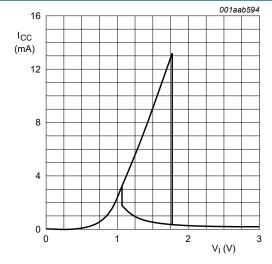


Fig. 16. Typical 74LVC1G57-Q100 transfer characteristic;  $V_{CC}$  = 3.0 V

# 13. Package outline

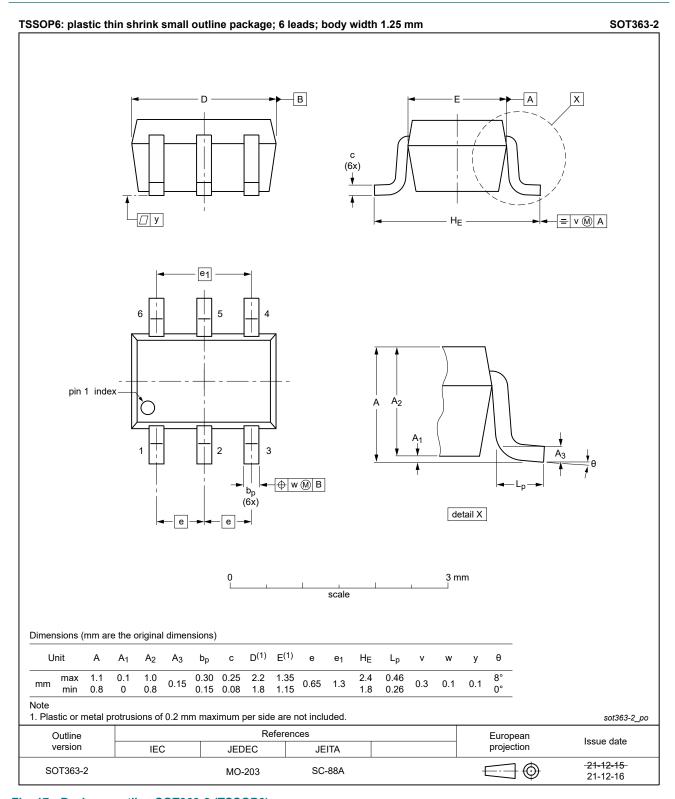


Fig. 17. Package outline SOT363-2 (TSSOP6)

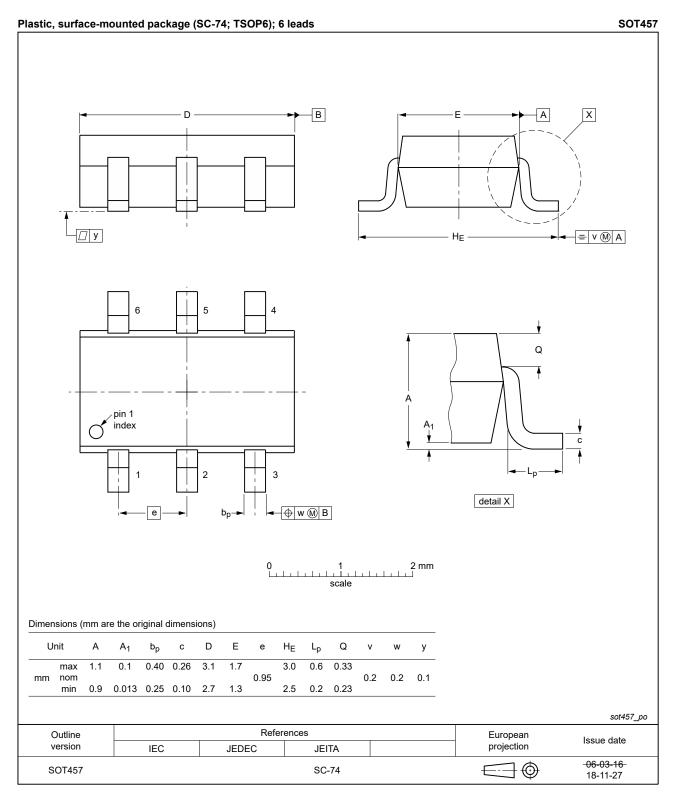


Fig. 18. Package outline SOT457 (SC-74; TSOP6)

## 14. Abbreviations

#### **Table 13. Abbreviations**

| Acronym | Description                             |
|---------|---|
| CMOS    | Complementary Metal Oxide Semiconductor |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| НВМ     | Human Body Model                        |
| TTL     | Transistor-Transistor Logic             |

# 15. Revision history

#### **Table 14. Revision history**

| Document ID        | Release date  | Data sheet status  | Change notice | Supersedes         |  |  |
|--------------------|---|--------------------|---------------|--------------------|--|--|
| 74LVC1G57_Q100 v.5 | 20230818  | Product data sheet | -             | 74LVC1G57_Q100 v.4 |  |  |
| Modifications:     | <u>Section 2</u> : ESD specification updated according to the latest JEDEC standard.  |                    |               |                    |  |  |
| 74LVC1G57_Q100 v.4 | 20220201  | Product data sheet | -             | 74LVC1G57_Q100 v.3 |  |  |
| Modifications:     | Package SOT363 (SC-88) changed to SOT363-2 (TSSOP6).  |                    |               |                    |  |  |
| 74LVC1G57_Q100 v.3 | 20210604  | Product data sheet | -             | 74LVC1G57_Q100 v.2 |  |  |
| Modifications:     | <ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Section 1 and Section 2 updated.</li> <li>Section 8: Derating values for P<sub>tot</sub> total power dissipation updated.</li> <li>Fig. 18: Package outline drawing SOT457 (SC-74; TSOP6) updated.</li> </ul> |                    |               |                    |  |  |
| 74LVC1G57_Q100 v.2 | 20161209  | Product data sheet | -             | 74LVC1G57_Q100 v.1 |  |  |
| Modifications:     | <u>Table 8</u> : The maximum limits for leakage current and supply current have changed.  |                    |               |                    |  |  |
| 74LVC1G57_Q100 v.1 | 20140415  | Product data sheet | -             | -                  |  |  |

## 16. Legal information

#### Data sheet status

| Document status [1][2]         | Product<br>status [3] | Definition  |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet   | Development           | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification         | This document contains data from the preliminary specification.                       |
| Product [short]<br>data sheet  | Production            | This document contains the product specification.                                     |

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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#### Low-power configurable multiple function gate

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74LVC1G57\_Q100

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